NSN 5962-01-341-5885

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View Online at https://aerobasegroup.com/nsn/5962-01-341-5885

Body Length:
0.460 inches
Body Width:
0.460 inches
Body Height:
0.155 inches
Maximum Power Dissipation Rating:
650.0 milliwatts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Burn in and programmed and ultraviolet erasable and monolithic and tested to mil-std-883
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Input Circuit Pattern:
22 input
Current Rating Per Characteristic:
100.00 milliamperes reverse current, dc absolute
Terminal Surface Treatment:
Solder
Product Name:
600 gate eraseble programmable logic device
Voltage Rating And Type Per Characteristic:
7.0 volts power source
Capitance Rating Per Characteristic:
20.00 input picofarads
Time Rating Per Chacteristic:
500.00 nanoseconds fall
Memory Device Type:
Eprom
Test Data Document:
96906-mil-std 883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
24 printed circuit
Shelf Life:

N/a

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Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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